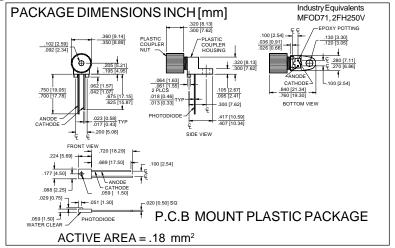
# PHOTONIC DETECTORS INC.

# Silicon Photodiode, Photoconductive **Fiber Optic Detector Type PDB-C505**





#### **FEATURES**

- High speed, 50 Mhz
- Low cost, PCB mount
- Includes connector
- Light tight package

#### **DESCRIPTION**

The **PDB-C505** is a high speed, PIN photodiode packaged in a low cost P.C.B mount plastic housing. Designed to interface with 1000 micron core plastic fiber for short haul fiber optic systems.Ideally matched with

## PDI-E508 IR or PDR-E509 red emitter.

# ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

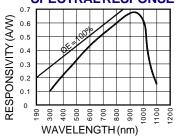
SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>BR</sub>	Reverse Voltage		100	V
P <sub>D</sub>	Total Power Dissipation		200	mW
То	Operating Temperature Range	-40	+80	∘C
Ts	Soldering Temperature*		+260	∘C
IL	Light Current		500	mA

<sup>\*1/16</sup> inch from case for 3 secs max

### **APPLICATIONS**

- High isolation interconnects
- Medical electronics
- Consumer electronics
- Micro processor

# **SPECTRAL RESPONSE**



#### **ELECTRO-OPTICAL CHARACTERISTICS** (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 1000 lux, 2850 K		10		<b>m</b> A
ΙD	Dark Current	$H = 0, V_R = 10 V$		.20	20	nA
Rsн	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$	500	1000		$M\Omega$
TC Rsh	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-10		%/℃
Сл	Junction Capacitance	$H = 0, V_R = 10 V^{**}$		5		pF
λrange	Spectral Application Range	Flooded D.C.	400		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	I = 10 <b>m</b> A	50	100		V
NEP	Noise Equivalent Power	V <sub>R</sub> = 10 V @ 850 nm		6x10 <sup>-15</sup>		W/ √Hz
tr	Response Time	$RL = 1 K\Omega V_R = 10 V$		6		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*\* f = 1 MHz